**Product data sheet** 

#### 1. **Product profile**

## 1.1 General description

Hyperfast, epitaxial rectifier diode in a SOD59 (2-lead TO-220AC) plastic package.

### 1.2 Features

- Extremely fast switching
- Reduces switching loss in associated **MOSFET**
- Low thermal resistance
- Low reverse recovery current

## 1.3 Applications

- Half-bridge or full-bridge switched-mode Continuous Current Mode (CCM) Power power supplies
- Half-bridge lighting ballasts
- Factor Correction (PFC)

### 1.4 Quick reference data

- $V_{RRM} \le 600 \text{ V}$
- $V_F = 1.54 \text{ V (typ)}$

- $I_{F(AV)} \le 20 \text{ A}$
- $t_{rr} = 19 \text{ ns (typ)}$

## **Pinning information**

Table 1. Pinning

| Pin | Description            | Simplified outline      | Symbol                             |
|-----|------------------------|-------------------------|------------------------------------|
| 1   | cathode (k)            | mb                      |                                    |
| 2   | anode (a)              |                         | k — <b>├</b> a<br><i>001aaa020</i> |
| mb  | mounting base; cathode |                         |                                    |
|     |                        |                         |                                    |
|     |                        |                         |                                    |
|     |                        |                         |                                    |
|     |                        | 1 2<br>TO-220AC (SOD59) |                                    |

## 3. Ordering information

### Table 2. Ordering information

| Type number | Package  |  |         |
|-------------|----------|--|---------|
|             | Name     | Description  | Version |
| BYC20-600   | TO-220AC | plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC | SOD59   |

## 4. Limiting values

### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol             | Parameter                       | Conditions  | Min | Max  | Unit |
|--------------------|---------------------------------|---|-----|------|------|
| $V_{RRM}$          | repetitive peak reverse voltage |   | -   | 600  | V    |
| $V_{RWM}$          | crest working reverse voltage   |   | -   | 600  | V    |
| $V_R$              | reverse voltage                 | square waveform; $\delta$ = 1.0; $T_{mb} \le 100$ °C                      | -   | 500  | V    |
| I <sub>F(AV)</sub> | average forward current         | square waveform; $\delta$ = 0.5; $T_{mb} \le 93$ °C                       | -   | 20   | Α    |
| I <sub>FRM</sub>   | repetitive peak forward current | square waveform; $\delta$ = 0.5; $T_{mb} \leq$ 93 °C; $t_p$ = 25 $\mu s;$ | -   | 40   | Α    |
| I <sub>FSM</sub>   | non-repetitive peak forward     | t = 10 ms; sinusoidal waveform  | -   | 250  | Α    |
|                    | current                         | t = 8.3 ms; sinusoidal waveform   | -   | 274  | Α    |
| T <sub>stg</sub>   | storage temperature             |   | -40 | +150 | °C   |
| Tj                 | junction temperature            |   | -   | 150  | °C   |
|                    |                                 |   |     |      |      |

## 5. Thermal characteristics

#### Table 4. Thermal characteristics

| Symbol         | Parameter   | Conditions                           | Min | Тур | Max | Unit |
|----------------|---|--------------------------------------|-----|-----|-----|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | with heatsink compound; see Figure 1 | -   | -   | 1.2 | K/W  |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient       | in free air                          | -   | 60  | -   | K/W  |

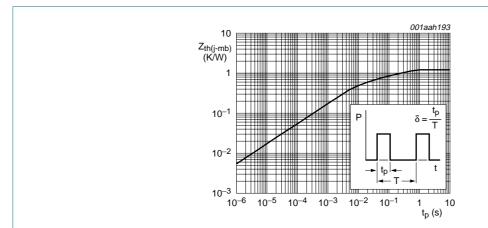


Fig 1. Transient thermal impedance from junction to mounting base as a function of pulse width

## 6. Characteristics

Table 5. Characteristics

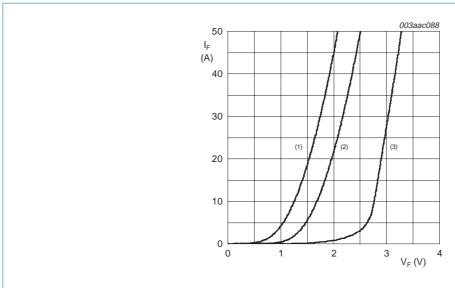
 $T_j = 25 \,^{\circ}C$  unless otherwise specified.

| Symbol          | Parameter                     | Conditions  | Min | Тур  | Max  | Unit |
|-----------------|-------------------------------|---|-----|------|------|------|
| Static char     | racteristics                  |   |     |      |      |      |
| $V_{F}$         | forward voltage               | $I_F = 20 \text{ A}; T_j = 150 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 2}}{}$                                       | -   | 1.54 | 1.97 | V    |
|                 |                               | $I_F = 40 \text{ A}$ ; $T_j = 150 ^{\circ}\text{C}$ ; see Figure 2  | -   | 1.95 | 2.34 | V    |
|                 |                               | I <sub>F</sub> = 20 A; see <u>Figure 2</u>  | -   | 1.89 | 2.9  | V    |
| $I_R$           | reverse current               | V <sub>R</sub> = 600 V  | -   | 16   | 200  | μΑ   |
|                 |                               | V <sub>R</sub> = 500 V; T <sub>j</sub> = 100 °C   | -   | 1.6  | 3.0  | mA   |
| Dynamic c       | haracteristics                |   |     |      |      |      |
| t <sub>rr</sub> | reverse recovery time         | $I_F$ = 1 A to $V_R$ = 30 V; $dI_F/dt$ = 50 A/ $\mu$ s; see Figure 3  | -   | 35   | 55   | ns   |
|                 |                               | $I_F = 20 \text{ A to } V_R = 400 \text{ V};$<br>$dI_F/dt = 500 \text{ A/}\mu\text{s}; \text{ see } \frac{\text{Figure 3}}{}$ |     |      |      |      |
|                 |                               | T <sub>j</sub> = 25 °C  | -   | 19   | -    | ns   |
|                 |                               | T <sub>j</sub> = 100 °C   | -   | 32   | 40   | ns   |
| I <sub>RM</sub> | peak reverse recovery current | $I_F$ = 20 A to $V_R$ = 400 V; $T_j$ = 125 °C; see Figure 3   |     |      |      |      |
|                 |                               | $dI_F/dt = 50 A/\mu s$  | -   | 3.0  | 7.5  | Α    |
|                 |                               | $dI_F/dt = 500 A/\mu s$   | -   | 9.5  | 12   | Α    |
| $V_{FR}$        | forward recovery voltage      | $I_F = 20 \text{ A}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; see Figure 4   | -   | 8    | 11   | V    |

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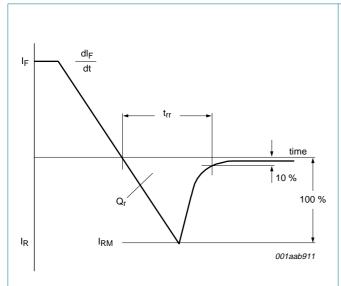
BYC20-600

Rectifier diode, hyperfast



- (1)  $T_j = 150 \,^{\circ}\text{C}$ ; typical values
- (2)  $T_j = 150 \,^{\circ}C$ ; maximum values
- (3)  $T_j = 25$  °C; maximum values

Fig 2. Forward current as a function of forward voltage





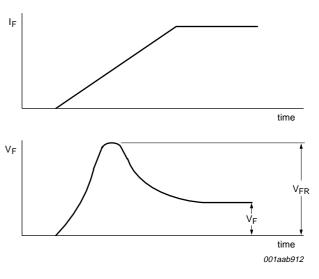
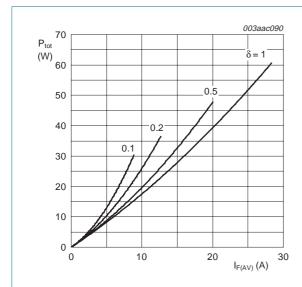


Fig 4. Forward recovery definitions

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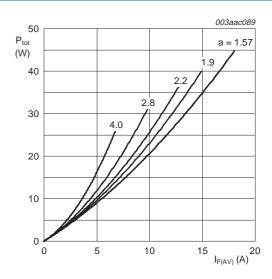
BYC20-600

## Rectifier diode, hyperfast



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ 

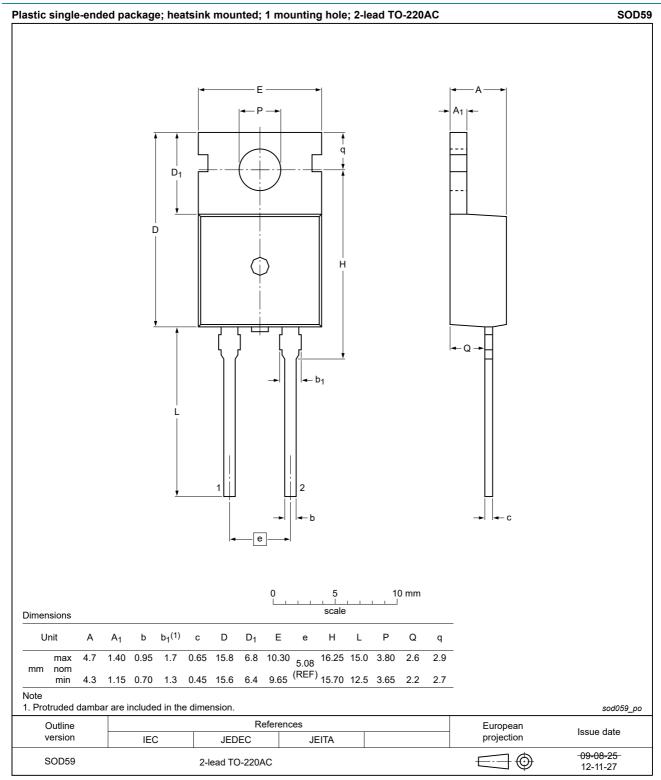
Fig 5. Forward power dissipation as a function of average forward current; square waveform; maximum values



 $a = form factor = I_{F(RMS)} / I_{F(AV)}$ 

Fig 6. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

## 7. Package outline



## 8. Legal information

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|--------------------------------------|--------------------|---|
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**BYC20-600** 

Rectifier diode, hyperfast

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